



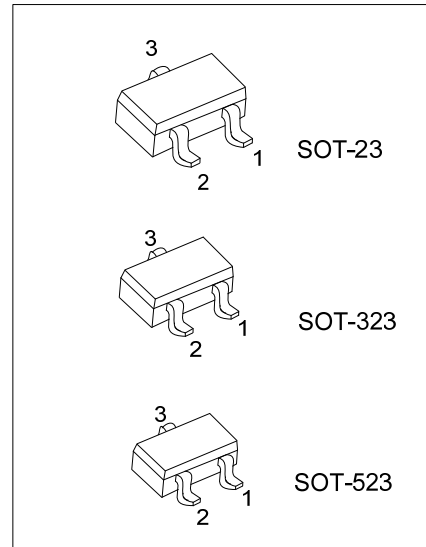
# 2SC4617

## NPN SILICON TRANSISTOR

### GENERAL PURPOSE TRANSISTOR

#### FEATURES

- \* Low Cob  
Cob=2.0pF (typ)
- \* Complements the UTC 2SA1774

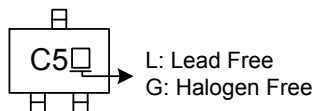


#### ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
2SC4617L-x-AE3-R	2SC4617G-x-AE3-R	SOT-23	E	B	C	Tape Reel
2SC4617L-x-AL3-R	2SC4617G-x-AL3-R	SOT-323	E	B	C	Tape Reel
2SC4617L-x-AN3-R	2SC4617G-x-AN3-R	SOT-523	E	B	C	Tape Reel

<p>2SC4617L-x-AE3-R</p> <p>(1) Packing Type (2) Package Type (3) Rank (4) Lead Free</p>	<p>(1) R: Tape Reel (2) AE3: SOT-23, AL3: SOT-323, AN3: SOT-523 (3) Refer to CLASSIFICATION OF H<sub>FE</sub> (4) L: Lead Free, G: Halogen Free</p>
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#### MARKING



■ ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		$V_{CBO}$	60	V
Collector-Emitter Voltage		$V_{CEO}$	50	V
Emitter-Base Voltage		$V_{EBO}$	7	V
Collector Current		$I_C$	0.15	A
Collector Power Dissipation	SOT-523	$P_C$	150	mW
	SOT-23/SOT-323	$P_C$	200	mW
Junction Temperature		$T_J$	+150	°C
Storage Temperature		$T_{STG}$	-55 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (Ta= 25°C, unless otherwise specified)

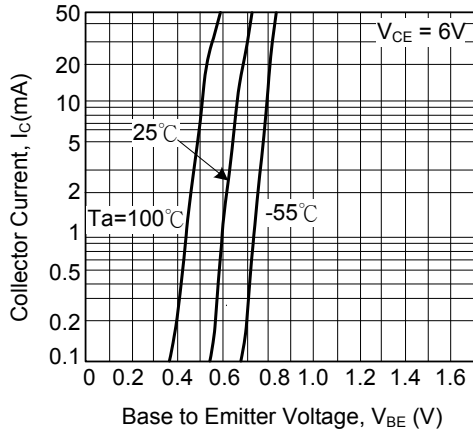
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Base Breakdown Voltage	$BV_{CBO}$	$I_C = 50\mu A$	60			V
Collector Emitter Breakdown Voltage	$BV_{CEO}$	$I_C = 1mA$	50			V
Emitter-base Breakdown Voltage	$BV_{EBO}$	$I_E = 50\mu A$	7			V
Collector Cut-Off Current	$I_{CBO}$	$V_{CB} = 60V$			0.1	$\mu A$
Emitter Cut-Off Current	$I_{EBO}$	$V_{EB} = 7V$			0.1	$\mu A$
DC Current Gain	$h_{FE}$	$V_{CE} = 6V, I_C = 1mA$	120		560	
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C = 50mA, I_B = 5mA$			0.4	V
Transition Frequency	$f_T$	$V_{CE} = 12V, I_E = -2mA, f = 100MHz$		180		MHz
Output Capacitance	$C_{ob}$	$V_{CE} = 12V, I_E = 0A, f = 1MHz$		2	3.5	pF

■ CLASSIFICATION OF  $h_{FE}$

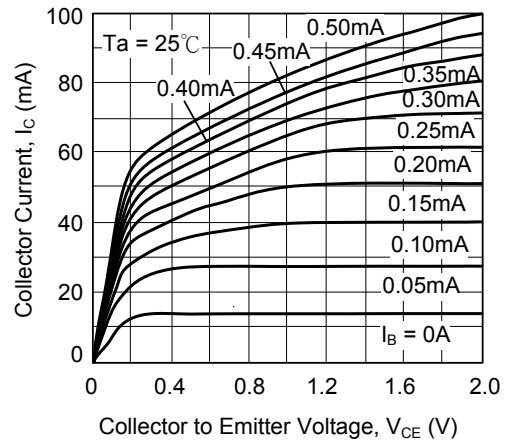
RANK	Q	R	S
RANGE	120 ~ 270	180 ~ 390	270 ~ 560

## TYPICAL CHARACTERISTICS

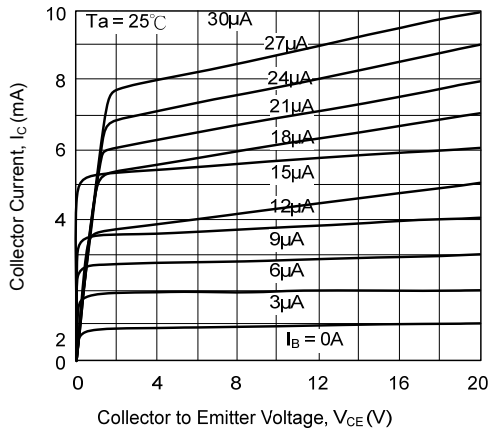
Grounded Emitter Propagation Characteristics



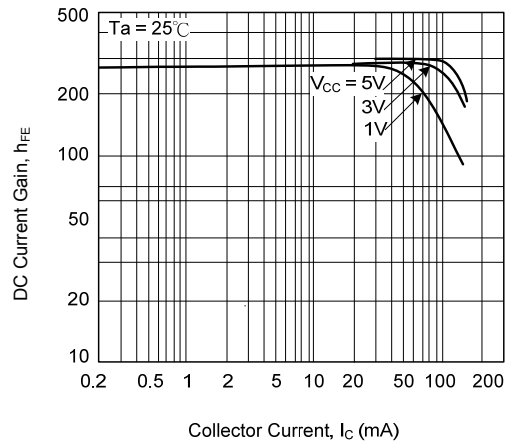
Grounded Emitter Output Characteristics (I)



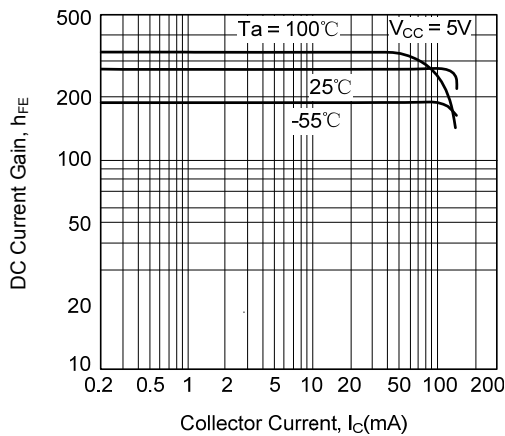
Grounded Emitter Output Characteristics (II)



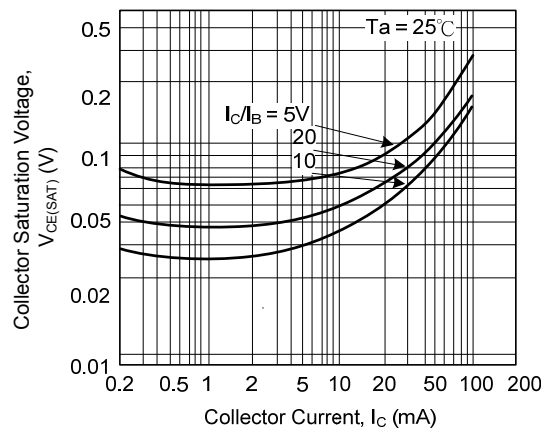
DC Current Gain vs. Collector Current (I)



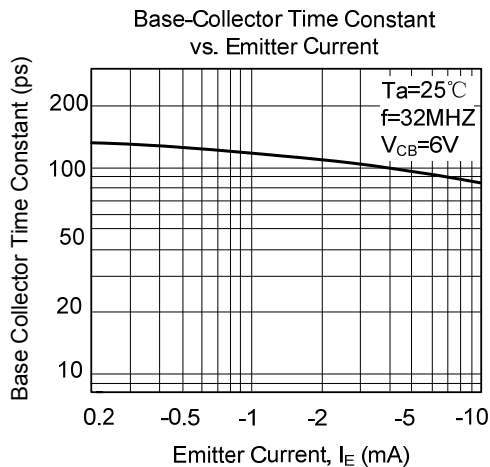
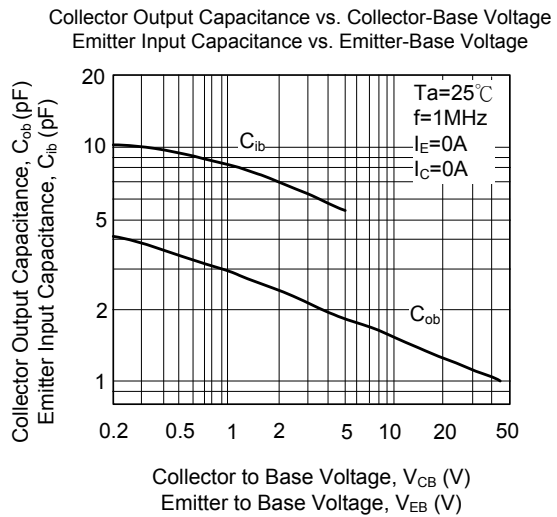
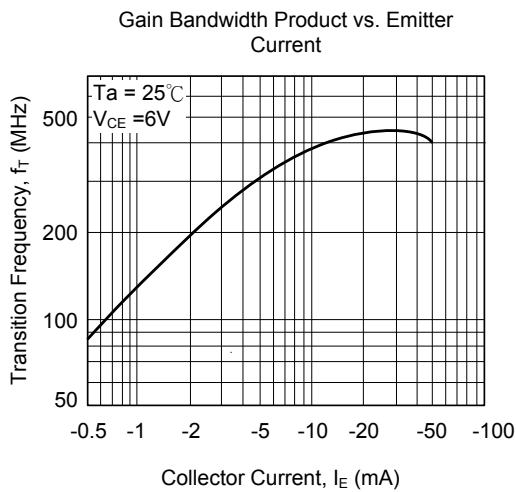
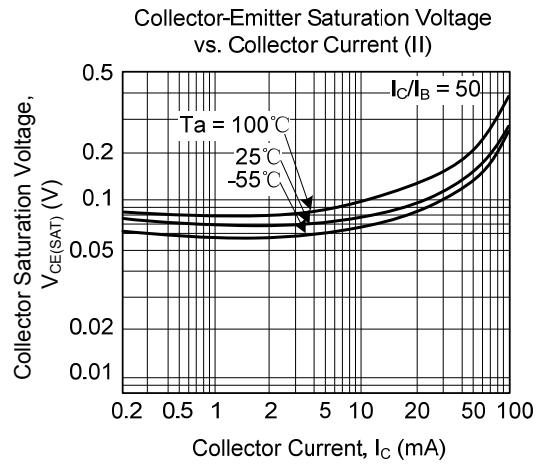
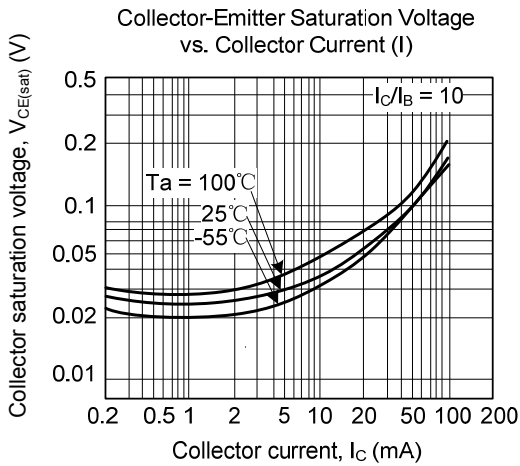
DC Current Gain vs. Collector Current (II)



Collector-Emitter Saturation Voltage vs. Collector Current



## TYPICAL CHARACTERISTICS



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